

SWITCHING
N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3640 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

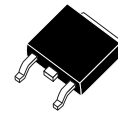
FEATURES

- Low on-state resistance
 $R_{DS(on)1} = 21 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 9 \text{ A)}$
 $R_{DS(on)2} = 40 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 9 \text{ A)}$
- Low C_{iss} : $C_{iss} = 570 \text{ pF TYP.}$
- Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3640-ZK	TO-252 (MP-3ZK)

(TO-252)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	30	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 16	V
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	± 19	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	± 76	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1}	20	W
Total Power Dissipation	P_{T2}	1.0	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	$-55 \text{ to } +150$	$^\circ\text{C}$
Single Avalanche Current ^{Note2}	I_{AS}	10	A
Single Avalanche Energy ^{Note2}	E_{AS}	10	mJ

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 15 \text{ V}$, $R_G = 25 \Omega$, $L = 100 \mu\text{H}$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

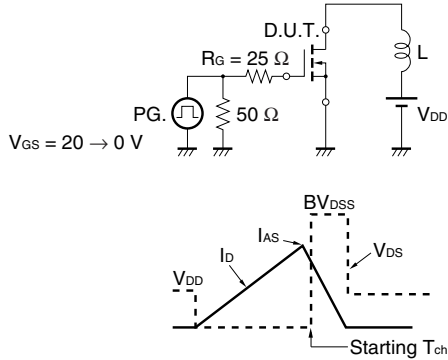
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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

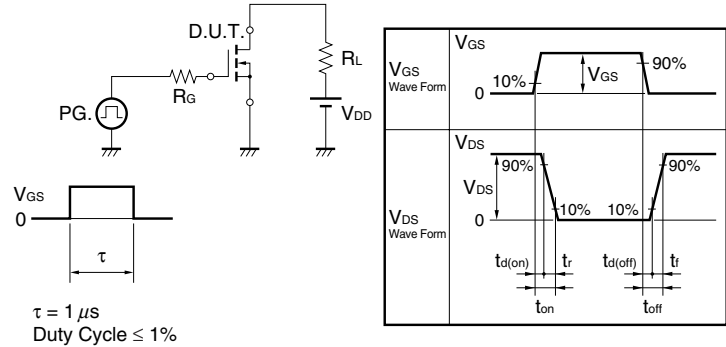
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$			10	μA
Gate Leakage Current	I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$			± 10	μA
Gate Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	1.5		2.5	V
Forward Transfer Admittance ^{Note}	$ y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 9\text{ A}$	3.7	7.4		S
Drain to Source On-state Resistance ^{Note}	$R_{DS(on)1}$	$V_{GS} = 10\text{ V}, I_D = 9\text{ A}$		15	21	$\text{m}\Omega$
	$R_{DS(on)2}$	$V_{GS} = 4.5\text{ V}, I_D = 9\text{ A}$		24	40	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS} = 10\text{ V}$		570		pF
Output Capacitance	C_{oss}	$V_{GS} = 0\text{ V}$		160		pF
Reverse Transfer Capacitance	C_{rss}	$f = 1\text{ MHz}$		100		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 15\text{ V}, I_D = 9\text{ A}$		7.7		ns
Rise Time	t_r	$V_{GS} = 10\text{ V}$		4.7		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 10\ \Omega$		24		ns
Fall Time	t_f			7		ns
Total Gate Charge	Q_G	$V_{DD} = 24\text{ V}$		14		nC
Gate to Source Charge	Q_{GS}	$V_{GS} = 10\text{ V}$		2.4		nC
Gate to Drain Charge	Q_{GD}	$I_D = 19\text{ A}$		4.3		nC
Body Diode Forward Voltage ^{Note}	$V_{F(S-D)}$	$I_F = 19\text{ A}, V_{GS} = 0\text{ V}$		0.95		V
Reverse Recovery Time	t_{rr}	$I_F = 19\text{ A}, V_{GS} = 0\text{ V}$		21		ns
Reverse Recovery Charge	Q_{rr}	$di/dt = 100\text{ A}/\mu\text{s}$		12		nC

Note Pulsed: $PW \leq 350\ \mu\text{s}$, Duty Cycle $\leq 2\%$

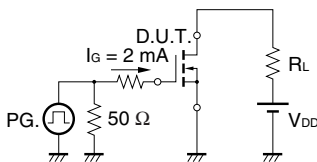
TEST CIRCUIT 1 AVALANCHE CAPABILITY



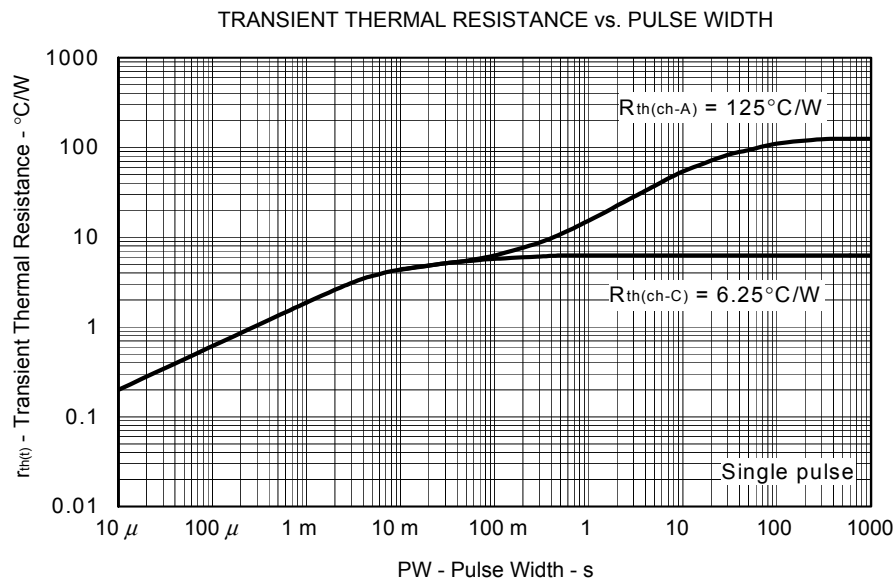
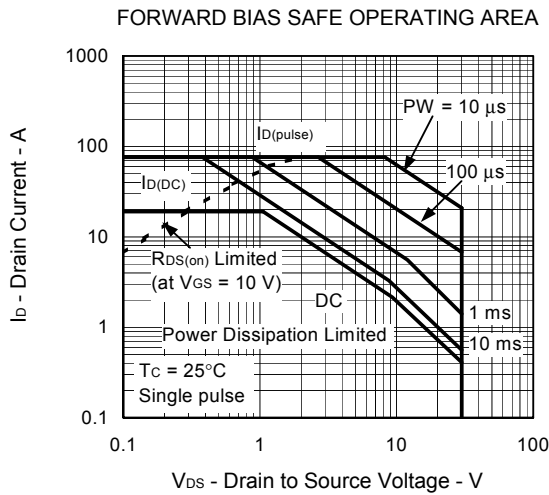
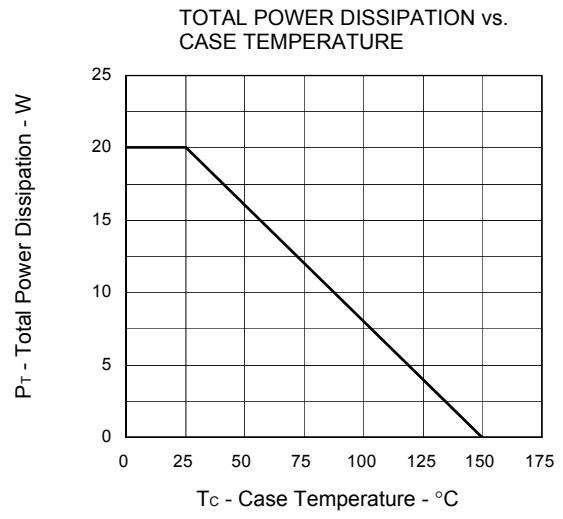
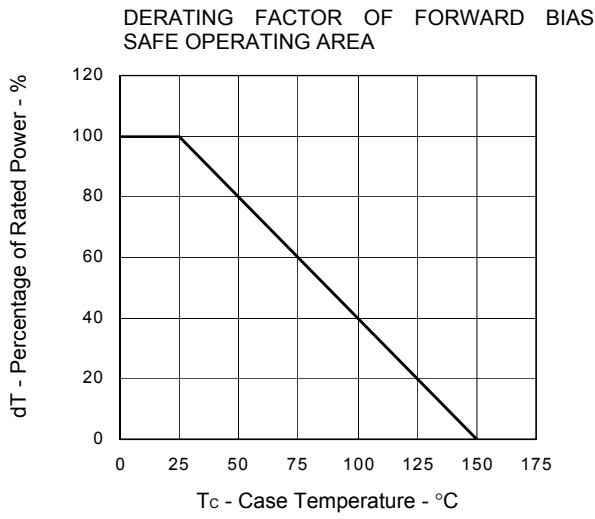
TEST CIRCUIT 2 SWITCHING TIME



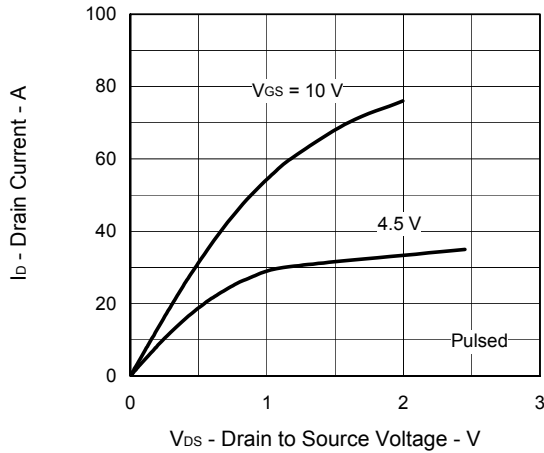
TEST CIRCUIT 3 GATE CHARGE



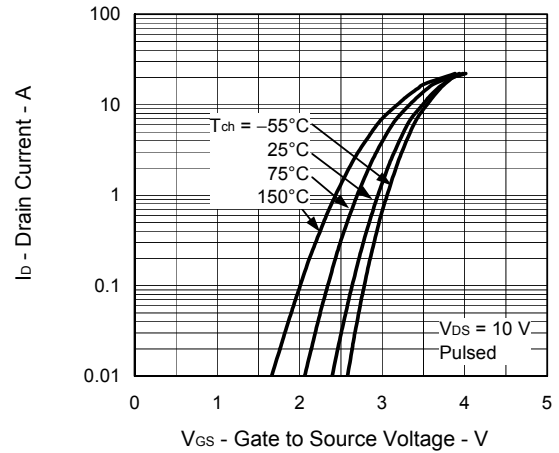
TYPICAL CHARACTERISTICS (T_A = 25°C)



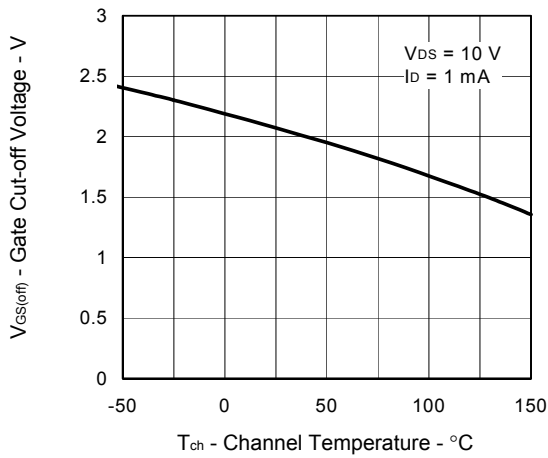
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



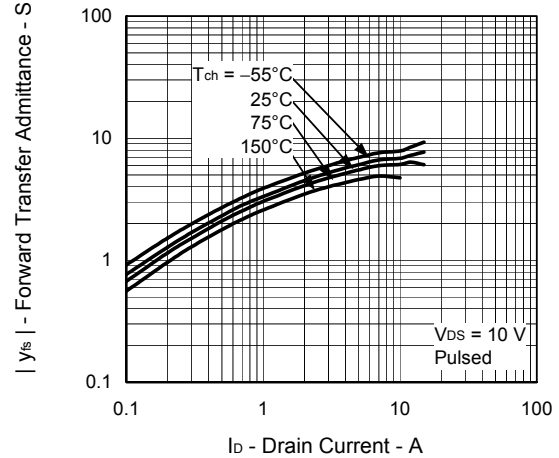
FORWARD TRANSFER CHARACTERISTICS



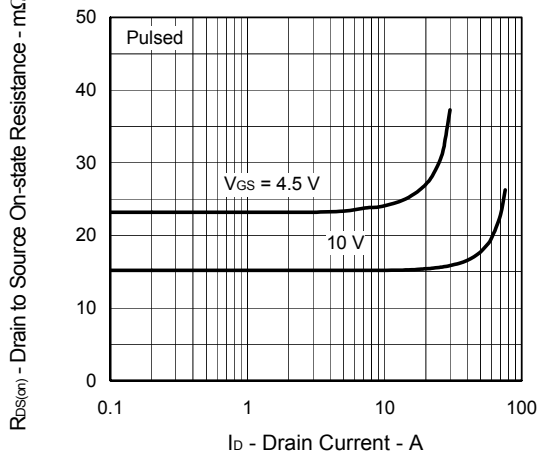
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



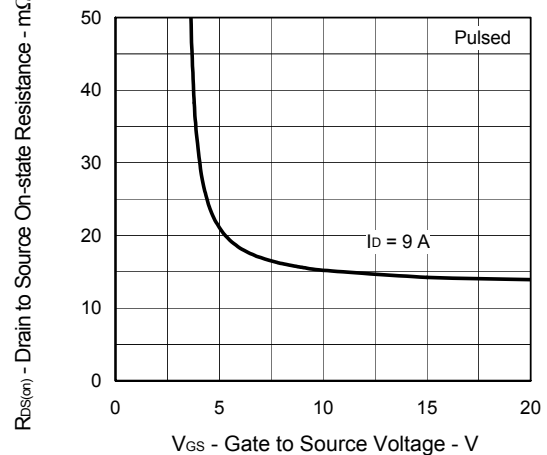
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



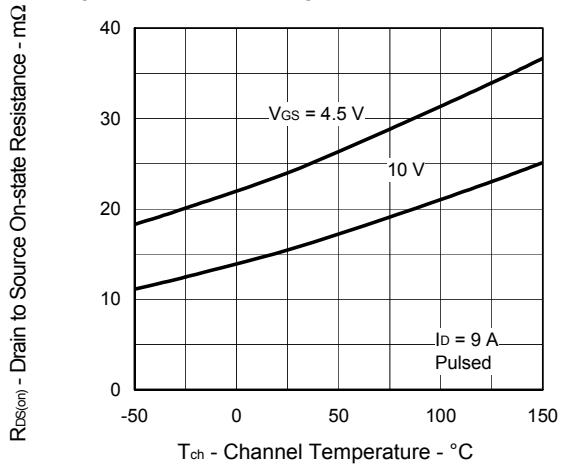
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



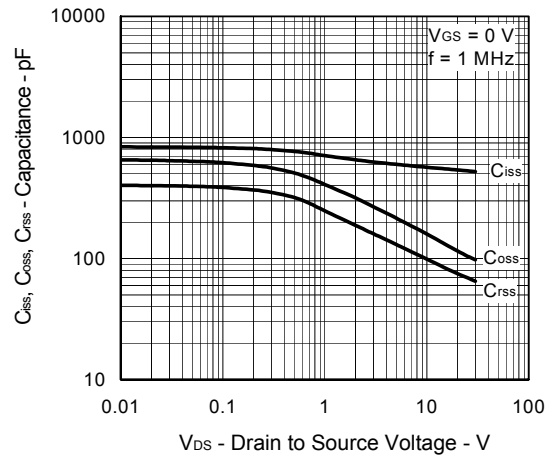
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



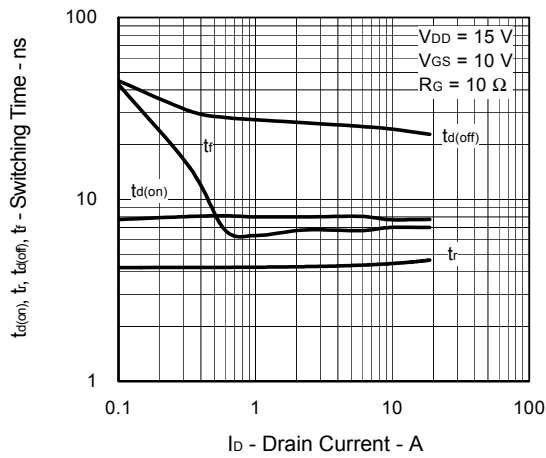
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



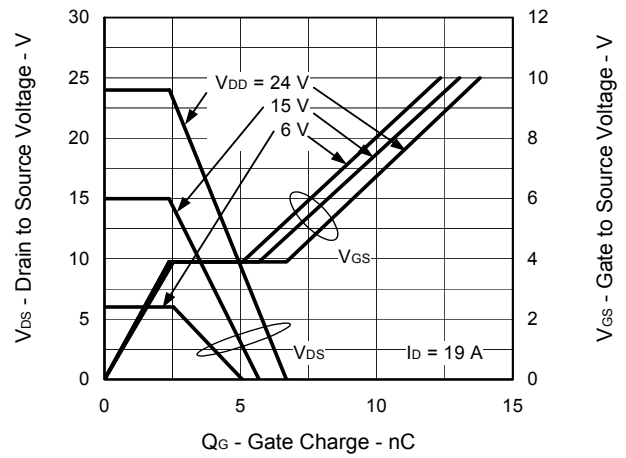
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



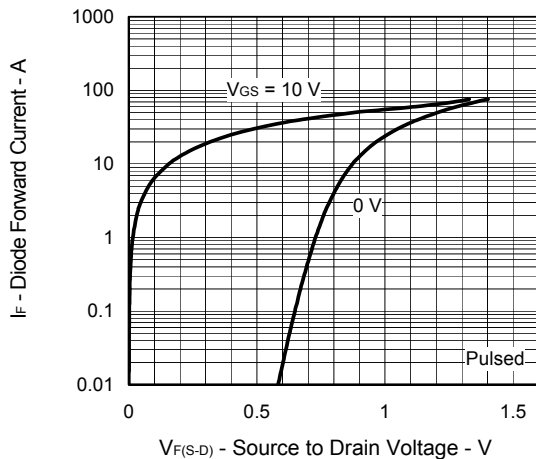
SWITCHING CHARACTERISTICS



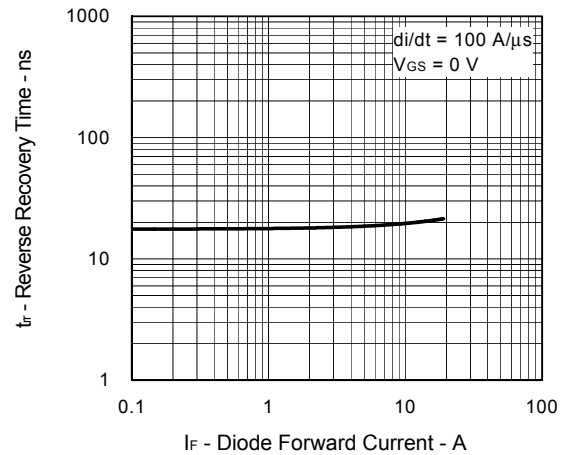
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



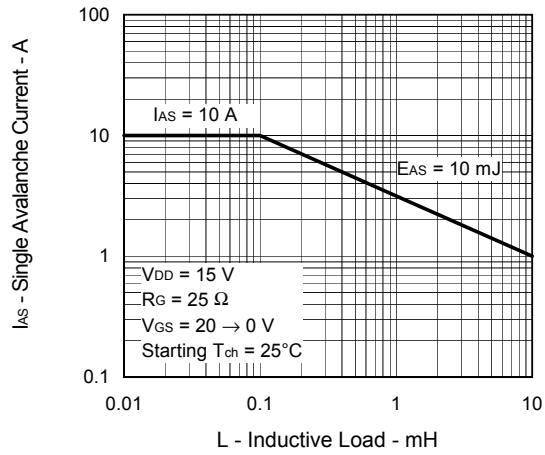
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



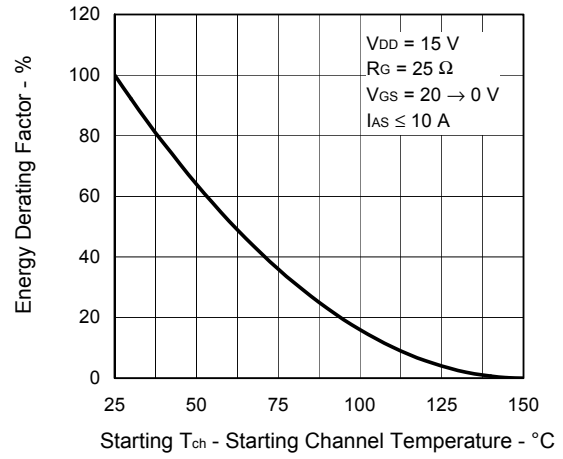
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY DERATING FACTOR



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